Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	4	(("5508533") or ("5614733") or ("6242290") or ("5986286")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/28 14:35
S2	44877	channel near2 width	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 14:57
S3	404	(257/213).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/25 14:58
S4	222171	"257".clas.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 14:58
S5	8602	S4 and S2	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:11
S6	50	S3 and S2	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 15:00
S7	2886291	typical common	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 15:00
S8	909	S2 with S7	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 15:00
S9	181	S8 and S4	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 15:06
S10	0	("semiconductoradjenergy.as.").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/25 15:06
S11	4537	"semiconductor energy".as.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 15:07
S12	11	S11 and S8	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 15:07
S13	3	("5147826" "5275851" "5358907"). PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/25 15:11
S14	910	S11 and S2	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 08:49
S15	62940	TFT	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 08:49

S16	3649	aluminium with crystallization	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 11:28
S17	9	(aluminium near3 crystallization) with promote	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 11:30
S18	169	((aluminium "Al" "W" "Mo" "Ta" tantulum tungsten molybdenum) near3 crystal\$7) with promot\$4	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 13:45
S19	3458011	bottom gate electrode	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 13:46
S20	463	bottom adj gate adj electrode	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 08:35
S21	150	S20 and TFT	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 13:46
S22	0	("sirringhaus.in.").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/28 15:01
S23	30	sirringhaus.in.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/28 15:01
S24	13165	((bottom back) near gate)	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 08:37
S25	70729	"TFT" (thin adj film adj transistor)	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:07
S26	2958	S24 same S25	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 08:38
S27	2823	S24 with S25	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 09:07
S28	404	(257/213).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/29 08:39
S29	11	S27 and S28	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 08:39
S30	8	("5079426" "5381014" "5396072" "5532180" "5614427" "5641974" "5650358" "5718800").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 08:42

		LASI Scarci	,			
S31	1158	(257/288).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/29 08:42
S32	10	S27 and S31	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 08:42
S33	11	S26 and S31	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 09:09
S34	2	("0000257").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/08/29 09:09
S35	222453	"257".clas.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 09:09
S36	1783	S35 and S27	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 09:12
S37	4058	nickel near concentration	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:07
S38	332	S37 and S26	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 09:13
S39	286	S38 and S35	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 09:13
S40	15	("4619034" "4746628" "4925812" "4943837" "4965213" "5064775" "5141880" "5147826" "5227315" "5248623" "5266507" "5275851" "5294555" "5300449" "5366912"). PŅ.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 09:46
S41	28	BCE near TFT	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 15:06
S42	1874	((back near channel near etch) (BCE))	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:06
S43	188	S42 and S25	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:06
S44	1	S43 and S37	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:07
S45	5216	nickel near2 concentration	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:07

S46	1	S43 and S45	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:07
S47	759201	nickel Ni	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:08
S48	31	S43 and S47	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:08
S49	2	("5825050" "6218219").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 10:16
S50	118	BCE and TFT	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 15:06
S51	4058	nickel near concentration	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 15:06
S52	1、	S50 and S51	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 15:06
S53	8	S50 and nickel	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/29 15:07
S54	152	("4746628" "5147826" "5275851" "5403772" "5426064").PN. OR ("5614733").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/08 14:48

			·-··			
S55	115	("3783049" "4059461" "4068020" "4132571" "4174217" "4226898"	US-PGPUB; USPAT;	OR	ON	2006/09/08 15:14
		1	USOCR			
		l	USUCK			
		"4300989" "4309224" "4331709" "4379020" "4409724" "4472210"				
		4379020				
		"4597160" "4634473" "4755481"				
		"4959247" "5043224" "5075259"				
		"5112764" "5145808" "5147826"				
		"5173446" "5194934" "5200630"				
		"5221423" "5225355" "5244836"				
		"5248630" "5252502" "5254480"				
		"5262350" "5262654" "5275851"				
ŀ		"5278093" "5289030" "5296405"				
		"5298075" "5308998" "5313075"				
		"5352291" "5358907" "5366926"				
		"5395804" "5403772" "5424230"				
		"5426064" "5480811" "5481121"				
		"5488000" "5492843" "5501989"		İ		
		"5508533" "5529937" "5531182"				
		"5534716" "5543352" "5550070"		[
		"5563426" "5569610" "5569936"				
		"5580792" "5585291" "5589694"				
		5560792		ĺ		
		"5605846" "5606179" "5608232"				
		"5612250" "5614426" "5614733"				
		"5616506" "5620910" "5621224"				
		"5624851" "5637515" "5639698"				
		"5643826" "5646424" "5654203"				
		"5656825" "5663077" "5677549"				
		"5696386" "5696388" "5700333"	-			
		"5705829" "5712191" "5756364"				
		"5923962" "RE28385" "RE28386").				
		PN. OR ("6413805").URPN.				
					_	
S56	0	"10.sup13"	US-PGPUB;	OR	ON	2006/09/08 16:02
			USPAT;			
-			USOCR	į		
S57	0	"10.sup13"	US-PGPUB;	OR	ON	2006/09/08 16:03
	J	10.3 dp. 13	USPAT;		0.1	2000/05/00 10:05
		·	USOCR			
S58	0	"10.sup13"	US-PGPUB;	OR	ON	2006/09/08 16:03
[USPAT;			
			USOCR			
S59	60844	leakage near current	US-PGPUB;	OR	ON	2006/09/08 16:03
	55011	- Tanago man admant	USPAT;	"``	0.1	2000,00,00 10.00
1	į		USOCR			
S60	4578	"semiconductor energy".as.	US-PGPUB;	OR	ON	2006/09/08 16:03
İ			USPAT;			
			USOCR			
S61	395	S59 and S60	US-PGPUB;	OR	ON	2006/09/12 08:44
			USPAT;		J.,	2000/03/12 00.14
			USOCR			
				L	l	<u> </u>

S62	2576	source\$1drain near voltage	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/12 08:45
S63	60915	leakage near current	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/12 08:45
S64	48	S62 with S63	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/12 08:45
S65	410	(257/213).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/09/12 09:25
S66	71088	TFT (thin adj film adj transistor)	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:07
S67	45115	channel near2 width	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:11
S68	3414	S67 and S66	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:12
S69	223580	"257".clas.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:12
S70	2026	S67 and S66 and S69	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:12
S71	1338	S67 same S66 and S69	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:12
S72	1099	S67 with S66 and S69	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/13 10:29
S73	1	("6194254").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/09/13 10:30